
Chapter 9

Publication

1. **Sambhab Dan**, et al. “*Unraveling the Obscure Electronic Transition and Tuning of Fermi Level in Cu Substituted Bi₂Te₃ Compound.*” *Applied Physics Letters* 120.2 (2022): 022105.
 2. **Sambhab Dan**, et al. “*Magnetotransport Properties and Fermi Surface Topology of Nodal line Semimetal InBi.*” *Physical Review B* 107.20 (2023): 205111.
 3. **Sambhab Dan**, et al. “*First Principle Study of the Defect-Induced Band Structure in Cu Substituted Bi₂Te₃ Topological Insulator.*” Book Chapter Springer Nature Publication, 2022 (Accepted).
 4. **Sambhab Dan**, et al. “*Experimental realization of non-trivial type-II Dirac Cone Protected By C₄ Symmetry in Nodal Line Semimetal InBi*” Manuscript under preparation (2023)
 5. D Pal... **Sambhab Dan**, et al. “*Multiple Magnetic Phases and Anomalous Hall Effect in Sb₁₋₉Fe₀₋₁Te₂₋₈₅S₀₋₁₅ Topological Insulators.*” *The Journal of Physical Chemistry*
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C 127.5 (2023): 2508-2517.

6. P. Singh... **Sambhab Dan**, et al. "*Double Glassy States and Large Spontaneous and Conventional Exchange Bias in $\text{La}_{1-x}\text{Ca}_x\text{CoFeO}_6$ Ferrimagnetic Double Perovskite.*" Journal of Physics: Condensed Matter 34.37 (2022): 375803.

7. D. Pal... **Sambhab Dan**, et al. "*Pressure-Induced Topological and Structural Transitions in Iron and Sulphur Doped Sb_2Te_3 .*" Materials Letters 302 (2021): 130401.

8. K. Anand... **Sambhab Dan**, et al. "*Emergence of metamagnetic Transition, Re-entrant Cluster Glass and Spin Phonon Coupling in $\text{Tb}_2\text{CoMnO}_6$.*" Journal of Physics: Condensed Matter 33.27 (2021): 275802.

9. D. Pal... **Sambhab Dan**, et al. "*Defect-induced Ferromagnetic Ordering and Room Temperature Negative Magnetoresistance in MoTeP .*" Scientific Reports 11.1 (2021): 9104.

10. D. Pal... **Sambhab Dan**, et al. "*Structural, Magnetic and Vibrational Properties of BSTS Topological Insulator.*" AIP Conference Proceedings. Vol. 2265. No. 1. AIP Publishing LLC, 2020.

11. D. Pal... **Sambhab Dan**, et al. "*Multiple Magnetic Phases and Anomalous Hall Effect in $\text{Sb}_{1.9}\text{Fe}_{0.1}\text{Te}_{2.85}\text{S}_{0.15}$ Topological Insulators*" the Journal of Physical Chemistry C 127.5 (2023): 2508-2517.

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